Preferred Device

Sensitive Gate Triacs

Silicon Bidirectional Thyristors

Designed for industrial and consumer applications for full wave control of ac loads such as appliance controls, heater controls, motor controls, and other power switching applications.

- Sensitive Gate allows Triggering by Microcontrollers and other Logic Circuits
- High Immunity to $dv/dt 25 V/\mu s$ minimum at $110^{\circ}C$
- High Commutating di/dt 8.0 A/ms minimum at 110°C
- Minimum and Maximum Values of I_{GT}, V_{GT} and I_H Specified for Ease of Design
- On-State Current Rating of 15 Amperes RMS at 70°C
- High Surge Current Capability 120 Amperes
- Blocking Voltage to 800 Volts
- Rugged, Economical TO220AB Package
- Uniform Gate Trigger Currents in Three Quadrants, Q1, Q2, and Q3
- Device Marking: Logo, Device Type, e.g., MAC15SD, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage(1) (T _J = -40 to 110°C, Sine Wave, 50 to 60Hz, Gate Open)	V _{DRM,} V _{RRM}		Volts
MAC15SD MAC15SM MAC15SN		400 600 800	
On–State RMS Current (Full Cycle Sine Wave, 60Hz, T _J = 70°C)	^I T(RMS)	15	A
Peak Non-repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, TJ = 110°C)	ITSM	120	A
Circuit Fusing Consideration (t = 8.3 ms)	l ² t	60	A ² s
Peak Gate Power (Pulse Width ≤ 1.0 μs, T _C = 70°C)	PGM	20	Watts
Average Gate Power (t = 8.3 ms, T _C = 70°C)	PG(AV)	0.5	Watts
Operating Junction Temperature Range	Tj	-40 to +110	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

(1) V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

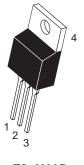


ON Semiconductor

http://onsemi.com

TRIACS 15 AMPERES RMS 400 thru 800 VOLTS







Main Terminal 1
Main Terminal 2
Gate
Main Terminal 2

ORDERING INFORMATION

Device	Package	Shipping
MAC15SD	TO220AB	50 Units/Rail
MAC15SM	TO220AB	50 Units/Rail
MAC15SN	TO220AB	50 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance			°C/W
— Junction to Case — Junction to Ambient	R _{θJC} R _{θJA}	2.0 62.5	
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

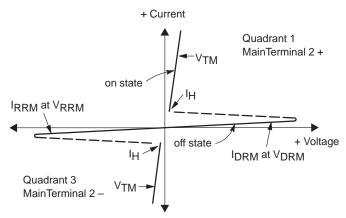
ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted; Electricals apply in both directions)

Characteristic		Min	Тур	Max	Unit
OFF CHARACTERISTICS					1
$ \begin{array}{l} \mbox{Peak Repetitive Blocking Current} \\ (V_D = Rated V_{DRM}, V_{RRM}; \mbox{Gate Open}) & T_J = 25^{\circ}\mbox{C} \\ T_J = 110^{\circ}\mbox{C} \end{array} $	I _{DRM} , I _{RRM}			0.01 2.0	mA
ON CHARACTERISTICS					
Peak On-State Voltage ⁽¹⁾ ($I_{TM} = \pm 21A$)	VTM	—	_	1.8	Volts
Gate Trigger Current (Continuous dc) ($V_D = 12 V$, $R_L = 100\Omega$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	IGT	.8 .8 .8	2.0 3.0 3.0	5.0 5.0 5.0	mA
Hold Current (V _D = 12 V, Gate Open, Initiating Current = \pm 150mA)	ΙΗ	1.0	3.0	10	mA
Latching Current ($V_D = 24V$, $I_G = 5mA$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	ιL	2.0 2.0 2.0	5.0 10 5.0	15 20 15	mA
Gate Trigger Voltage (Continuous dc) ($V_D = 12 V$, $R_L = 100\Omega$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	V _{GT}	0.45 0.45 0.45	0.62 0.60 0.65	1.5 1.5 1.5	Volts
DYNAMIC CHARACTERISTICS				•	
Rate of Change of Commutating Current (V _D = 400V, I _{TM} = 3.5A, Commutating dv/dt = 10V μ /sec, Gate Open, T _J = 110°C, f= 500Hz, Snubber: C _S = 0.01 μ F, R _S =15 Ω , see Figure 15.)	(di/dt)c	8.0	10	_	A/ms
Critical Rate of Rise of Off-State Voltage (V_D = Rate V_{DRM} , Exponential Waveform, R_{GK} = 510 Ω , T_J = 110°C)	dv/dt	25	75	-	V/µs

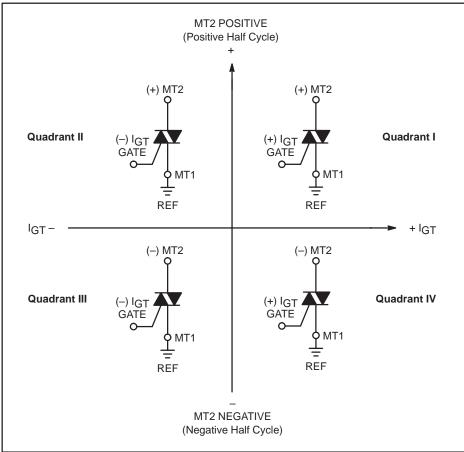
(1) Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
VTM	Maximum On State Voltage
Ι _Η	Holding Current

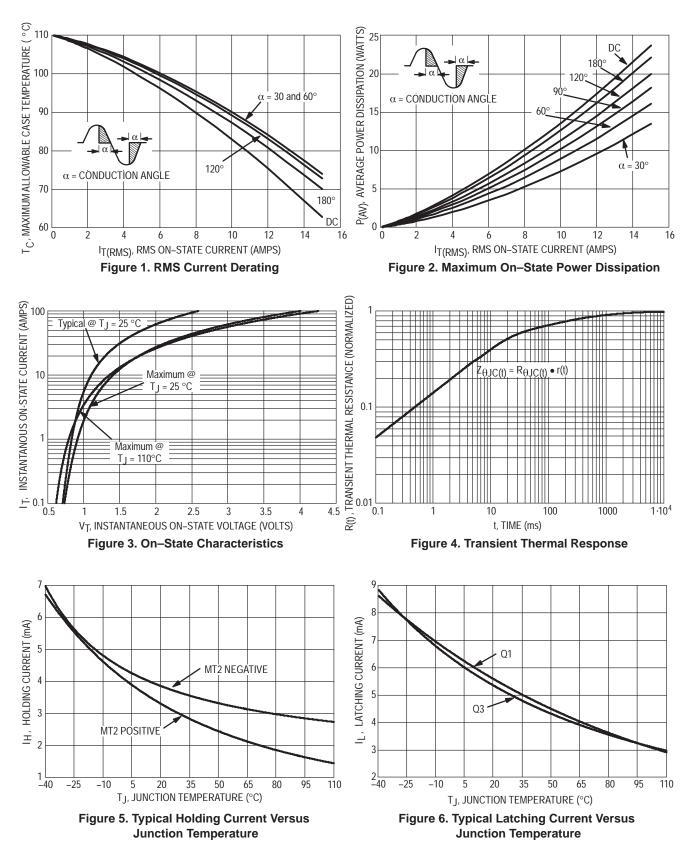


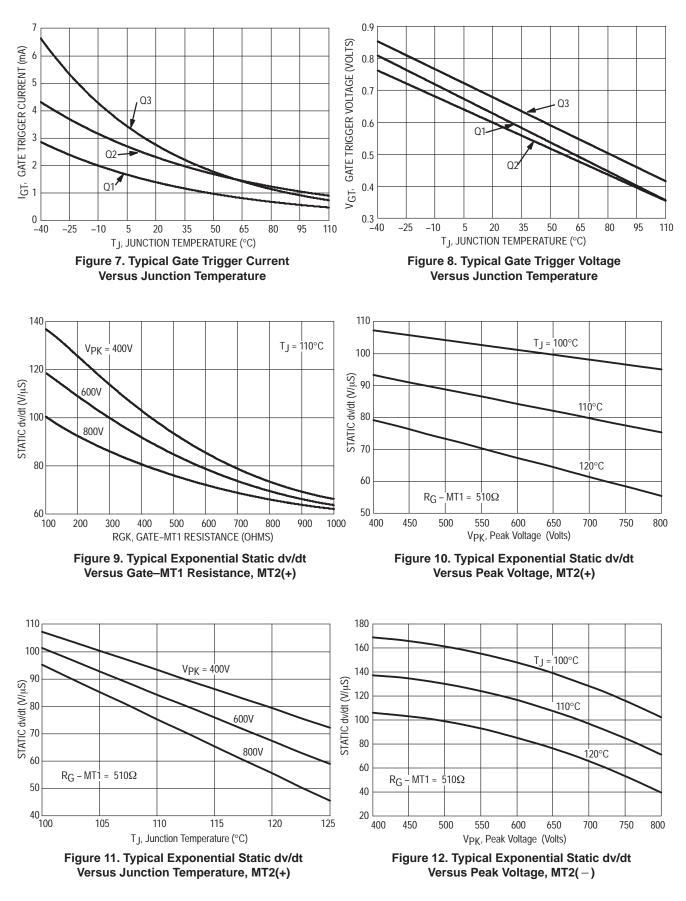
Quadrant Definitions for a Triac

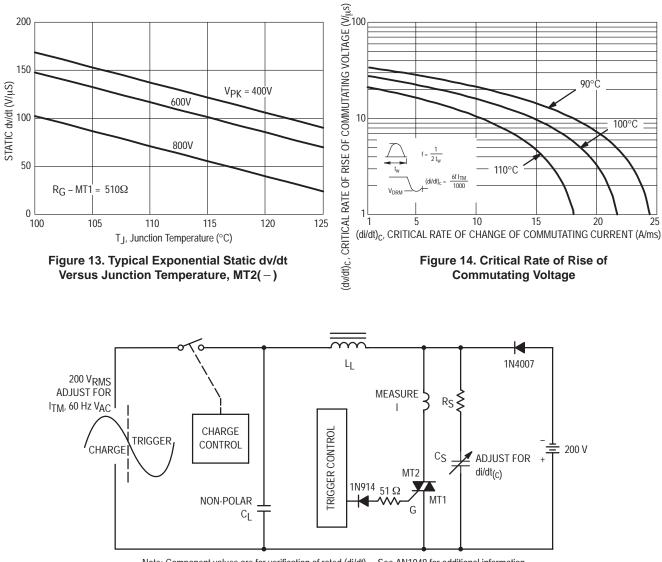


All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.





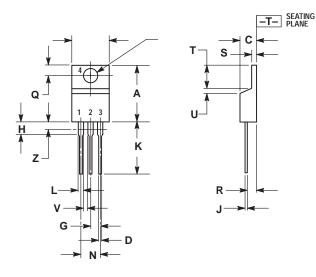


Note: Component values are for verification of rated $(di/dt)_{C}$. See AN1048 for additional information.

Figure 15. Simplified Test Circuit to Measure the Critical Rate of Rise of Commutating Current (di/dt)_C

PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 **ISSUE Z**



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.018	0.025	0.46	0.64	
К	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
Ν	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
V	0.045		1.15		
Z		0.080		2.04	

STYLE 4: PIN 1. MAIN TERMINAL 1 2. MAIN TERMINAL 2 3. GATE 4. MAIN TERMINAL 2

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